NSN 5961-01-125-6917

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Inclosure Material:

Metal

Overall Length:

1.570 inches

Overall Height:

Between 0.762 inches and 0.800 inches

Overall Width:

Between 0.990 inches and 1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-80.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between -1.30 amperes source cutoff current and -50.00 amperes source cutoff current

Power Rating Per Characteristic:

300.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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